

BZT52C2V4S THRU BZT52C43S

RoHS

Technical Data Data Sheet N1449, Rev. B

## BZT52C2V4S-BZT52C43S ZENER DIODES



## Schematic & Pin Configuration

# Cathode Anode

### Features

- Planar Die Construction
- 200mW Power Dissipation
- General purpose, medium current
- Ideally suited for automated assembly processes
- Available in lead free version
- This is a Halogen Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Mechanical Characteristics**

- Case: SOD-323, Molded plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.04 grams(approx)

### Maximum Ratings @T<sub>A</sub>=25°C unless otherwise specified

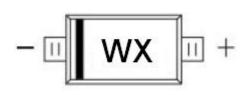
Characteristic	Symbol	Value	Units
Forward Voltage (Note 2) @ I <sub>F</sub> = 10mA	VF	0.9	V
Power Dissipation (Note 1)	PD	200	mW
Thermal Resistance from Junction to Ambient	R <sub>OJA</sub>	625	°C/W
Junction Temperature	TJ	150	°C
Storage Temperature Range	T <sub>STG</sub>	-55 to +150	°C

## **Ordering Information**

Device	Package	Shipping
BZT52C2V4S- BZT52C43S	SOD-323	3000pcs / reel
BZT52C2V4STR- BZT52C43STR	SOD-323	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## **Marking Diagram**



WX = Marking Code

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### BZT52C2V4S THRU BZT52C43S

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Electrical Characteristics @T <sub>A</sub> =25°C unless otherwise specified													
түре	Marking	Zener Voltage Range (Note 2)			Maximum Zener Impedance (Note 3)			Maximum Reverse Current (Note 2)		Typical Temperature Coefficient @ <sub>ZTC</sub> mV/ <b>C</b>		Test Current । टाट	
			Vz@lzt		I <sub>ZT</sub>	Z <sub>ZT</sub> @J <sub>ZT</sub> Z <sub>ZK</sub> @J <sub>ZK</sub> I <sub>ZK</sub>			I <sub>R</sub> V <sub>R</sub>				8
		Nom(V)	Min(V)	Max(V)	(mA)		Ω	(mA)	μA	v	Min	Max	mA
BZT52C2V4S	WX	2.4	2.20	2.60	5	100	600	1.0	50	1.0	-3.5	0	5
BZT52C2V7S	WI	2.7	2.5	2.9	5	100	600	1.0	20	1.0	-3.5	0	5
BZT52C3V0S	W2	3.0	2.8	3.2	5	95	600	1.0	10	1.0	-3.5	0	5
BZT52C3V3S	V\8	3.3	3.1	3.5	5	95	600	1.0	5	1.0	-3.5	0	5
BZT52C3V6S	V\4	3.6	3.4	3.8	5	90	600	1.0	5	1.0	-3.5	0	5
BZT52C3V9S	V\6	3.9	3.7	4.1	5	90	600	1.0	3	1.0	-3.5	0	5
BZT52C4V3S	W6	4.3	4.0	4.6	5	90	600	1.0	3	1.0	-3.5	0	5
BZT52C4V7S	W7	4.7	4.4	5.0	5	80	500	1.0	3	2.0	-3.5	0.2	5
BZT52C5∨1S	V\8	5.1	4.8	5.4	5	60	480	1.0	2	2.0	-2.7	1.2	5
BZT52C5V6S	V\9	5.6	5.2	6.0	5	40	400	1.0	1	2.0	-2	2.5	5
BZT52C6V2S	WA	6.2	5.8	6.6	5	10	150	1.0	3	4.0	0.4	3.7	5
BZT52C6V8S	WB	6.8	6.4	7.2	5	15	80	1.0	2	4.0	1.2	4.5	5
BZT52C7∨5S	WC	7.5	7.0	7.9	5	15	80	1.0	1	5.0	2.5	5.3	5
BZT52C8V2S	WD	8.2	7.7	8.7	5	15	80	1.0	0.7	5.0	3.2	6.2	5
BZT52C9V1S	WE	9.1	8.5	9.6	5	15	100	1.0	0.5	6.0	3.8	7.0	5
BZT52C10S	WF	10	9.4	10.6	5	20	150	1.0	0.2	7.0	4.5	8.0	5
BZT52C11S	WG	11	10.4	11.6	5	20	150	1.0	0.1	8.0	5.4	9.0	5
BZT52C12S	WH	12	11.4	12.7	5	25	150	1.0	0.1	8.0	6.0	10.0	5
BZT52C13S	W	13	12.4	14.1	5	30	170	1.0	0.1	8.0	7.0	11.0	5
BZT52C15S	WJ	15	13.8	15.6	5	30	200	1.0	0.1	10.5	9.2	13	5
BZT52C16S	WK	16	15.3	17.1	5	40	200	1.0	0.1	11.2	10.4	14	5
BZT52C18S	VVL.	18	16.8	19.1	5	45	225	1.0	0.1	12.6	12.4	16	5
BZT52C20S	VVM	20	18.8	21.2	5	55	225	1.0	0.1	14.0	14.4	18.0	5
BZT52C22S	WN	22	20.8	23.3	5	55	250	1.0	0.1	15.4	16.4	20.0	5
BZT52C24S	WO	24	22.8	25.6	5	70	250	1.0	0.1	16.8	18.4	22.0	5
BZT52C27S	WP	27	25.1	28.9	2	80	300	0.5	0.1	18.9	21.4	25.3	2
BZT52C30S	WQ	30	28.0	32.0	2	80	300	0.5	0.1	21.0	24.4	29.4	2
BZT52C33S	WR	33	31.0	35.0	2	80	325	0.5	0.1	23.1	27.4	33.4	2
BZT52C36S	WS	36	34.0	38.0	2	90	350	0.5	0.1	25.2	30.4	37.4	2
BZT52C39S	WT	39	37.0	41.0	2	130	350	0.5	0.1	27.3	33.4	41.2	2
BZT52C43S	WU	43	40.0	46.0	2	100	700	1	0.1	32	10	12	5

Notes: 1. Device mounted on ceramic PCB: 7.6mm x 9.4mm x 0.87mm with pad areas 25mm2 .

Short duration test pulse used to minimize self-heating effect.
 f = 1kHz.

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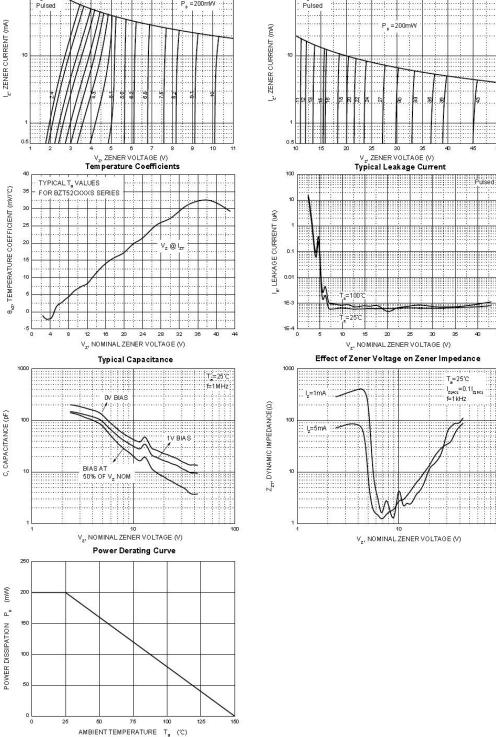


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Zener Characteristics (11 V to 43 V)

## RoHS HF

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100

T\_=25°C

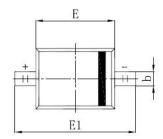
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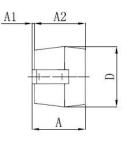


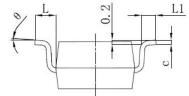
### BZT52C2V4S THRU **BZT52C43S**

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### **Mechanical Dimensions SOD-323**

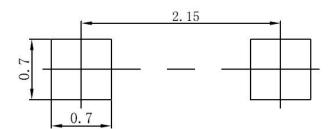






	Millim	neters	Inches			
SYMBOL	MIN.	MAX.	MIN.	MAX.		
A	-	1.000	-	0.039		
A1	0.000	0.100	0.000	0.004		
A2	0.800	0.900	0.031	0.035		
b	0.250	0.350	0.010	0.014		
с	0.080	0.150	0.003	0.006		
D	1.200	1.400	0.047	0.055		
E	1.600	1.800	0.063	0.071		
E1	2.500	2.700	0.098	0.106		
L	0.475	REF.	0.019 REF.			
L1	0.250	0.400	0.010	0.016		
θ	0°	8°	0°	8°		

### **SOD-323 Suggested Pad Layout**



### Note:

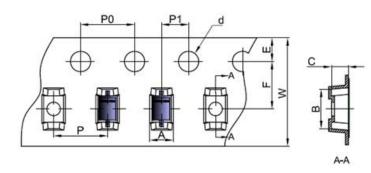
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1.Controlling dimension:in millimeters.

2.General tolerance:±0.05mm.

3. The pad layout is for reference purposes only.

### **Carrier Tape Specification SOD-323**



SYMBOL	Millimeters					
STWIDOL	Min.	Max.				
В	2.85	2.95				
С	1.20	1.30				
d	1.40	1.60				
E	1.65	1.85				
F	3.40	3.60				
Р	3.90	4.10				
P0	3.90	4.10				
P1	1.90	2.10				
W	7.90	8.30				

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